

600mA 10kV -High Voltage Power Diodes

High reliability resin molded type high voltage diode in small size package which is sealed a multilayed mesa type silicon chip by epoxy resin.

Features

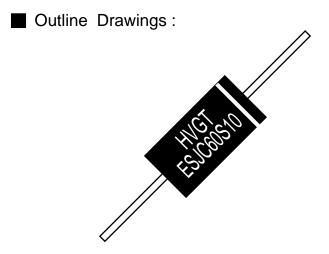
- High speed switching
- Epoxy resin molded in vacuum, Have anticorrosion in the surface
- High surge resisitivity for CRT discharge
- High reliability design
- Avalanche characteristic

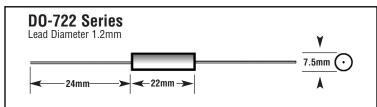
Applications

- X light Power supply
- Laser
- Voltage doubler circuit
- Microwave emission power
- General purpose high voltage rectifier, Voltage multiplier assembly.

Maximum Ratings and Characteristics

Absolute Maximum Ratings





Items	Symbols	Condition	ESJC60S10	Units
Repetitive Peak Renerse Voltage	V_{RRM}	Ta=25°C, IR =0.1mA	10	kV
Average Output Current	lo	Ta=25°C,Resistive Load	0.6	A peak
Suege Current	I _{FSM}	Ta=25°C,8.3msec, half sine	30	A peak
Junction Temperature	Tj		125	°C
Allowable Operation Case Temperature	Тс		125	°C
Storage Temperature	Tstg		-40 to +125	°C

• Electrical Characteristics (Ta=25°C Unless otherwise specified)

GETE ELECTRONIC CO.,LTD

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Items	Symbols	Conditions	ESJC60S10	Units
Maximum Forward Voltage Drop	VF	at 25°C, at: I₅	12	V
Maximum Reverse Current	IR1	at 25°C,VR =VRRM	5.0	uA
	IR2	at 100°C,VR =VRRM	50	uA
Maximum Reverse Recovery Time	Trr	at 25°C; F = 0.5 R; R = F(AV); Irr = 0.25 R		nS
Junction Capacitance	Cj	at 25°C;V _R =0V,f=1MHz		pF